

Microsemi.

Power Matters[™]

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- ▶ Parametric Search

Overview Diagrams

Electrical Rating Symbol Min Typ Max Unit DC Current Gain HFE 30.00 120.00 Turn Off Time (nS) t_{off} 1250.00 ns

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Collector Current (dc)	I _C			25.00	Α
Collector-Emitter Voltage (Base Open)	V _{CEO}			120.00	V
Junction Temperature (°C)	TJ			200.00	°C

This part can be found in the following product categories:

- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ PNP Transistor
- Discretes ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ PNP Transistor

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